CMOS Delay-7 (H.8) Delay Model

20170201

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References

Some Figures from the following sites

[1] http://pages.hmc.edu/harris/cmosvlsi/4e/index.html
Weste & Harris Book Site

[2] en.wikipedia.org

β : Device Transconductance Parameter
k : Process Transconductance Parameter
μ : Electron / Hole Mobility

pMOS $\quad \beta_p = k'_p \left(\frac{W}{L}\right)_p \qquad k'_p = \mu_p C_{ox} \qquad C_{ox} = \frac{\varepsilon_{ox}}{t_{ox}}$

nMOS $\quad \beta_n = k'_n \left(\frac{W}{L}\right)_n \qquad k'_n = \mu_n C_{ox} \qquad C_{ox} = \frac{\varepsilon_{ox}}{t_{ox}}$

pMOS $\quad \beta_p = \mu_p \frac{\varepsilon_{ox}}{t_{ox}} \left(\frac{W}{L}\right)_p$

nMOS $\quad \beta_n = \mu_n \frac{\varepsilon_{ox}}{t_{ox}} \left(\frac{W}{L}\right)_n$

Saturation Current

$$I_{dp} = \frac{\beta_p}{2} \left(V_{GSn} - |V_{Tp}|\right)^2 \qquad V_{Tp} < 0$$

$$I_{dn} = \frac{\beta_n}{2} \left(V_{GSn} - V_{Tn}\right)^2 \qquad V_{Tn} > 0$$

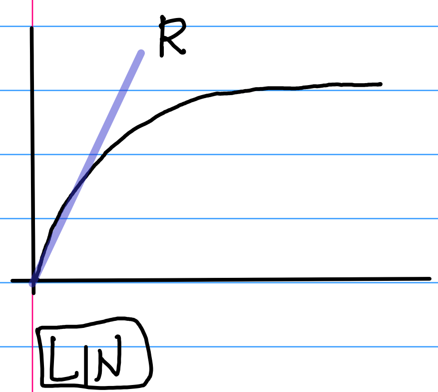
MODEL

$$\frac{\beta_n}{\beta_p} \simeq \frac{k'_n \left(\frac{W}{L}\right)_n}{k'_p \left(\frac{W}{L}\right)_p}$$

$$\frac{k'_n}{k'_p} = 2 \sim 3$$

$$\frac{k'_n}{k'_p} = \frac{\mu_n}{\mu_p} = r$$

$$\frac{\beta_n}{\beta_p} = \frac{k'_n \left(\frac{W}{L}\right)_n}{k'_p \left(\frac{W}{L}\right)_p}$$



$$R_n = \frac{1}{\beta_n (V_{DD} - V_{Tn})}$$

$$R_p = \frac{1}{\beta_n (V_{DD} - V_{Tn})}$$

fall time t_f $\quad \tau_n = R_n C_{out}$

rise time t_r $\quad \tau_p = R_p C_{out}$

$$C_{out} = C_{para} + C_L$$

MODEL

fall time	$t_f = 2.2\,\tau_n = \ln 9\,\tau_n$	$0.9\,V_{DD} \rightarrow 0.1\,V_{DD}$
rise time	$t_r = 2.2\,\tau_p = \ln 9\,\tau_p$	$0.1\,V_{DD} \rightarrow 0.9\,V_{DD}$
propagation delay time	$t_p = \frac{1}{2}(t_{pf} + t_{pr})$ $= 0.35(t_{pf} + t_{pr})$	$0.5\,V_{DD} \rightarrow 0.5\,V_{DD}$
propagation fall time	$t_{pf} = 0.7\,\tau_n = \ln 2\,\tau_n$	$V_{DD} \rightarrow 0.5\,V_{DD}$
propagation rise time	$t_{pr} = 0.7\,\tau_p = \ln 2\,\tau_p$	$0 \rightarrow 0.5\,V_{DD}$

$$\tau_n = R_n(C_{para} + C_L)$$

$$\tau_p = R_p(C_{para} + C_L)$$

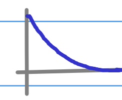
$$C_{out} = C_{para} + C_L$$

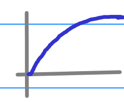
$$\left(\frac{W}{L}\right)_p = r\left(\frac{W}{L}\right)_n$$

$$r = \frac{\mu_n}{\mu_p} = \frac{k'_n}{k'_p} > 1$$

$$R_n = R_p = R = \frac{1}{\beta(V_{DD} - V_T)}$$

$$\begin{cases} V_{out}(t) = V_{DD}\left(1 - e^{-t/\tau}\right) \\ V_{out}(t) = V_{DD}\, e^{-t/\tau} \end{cases}$$





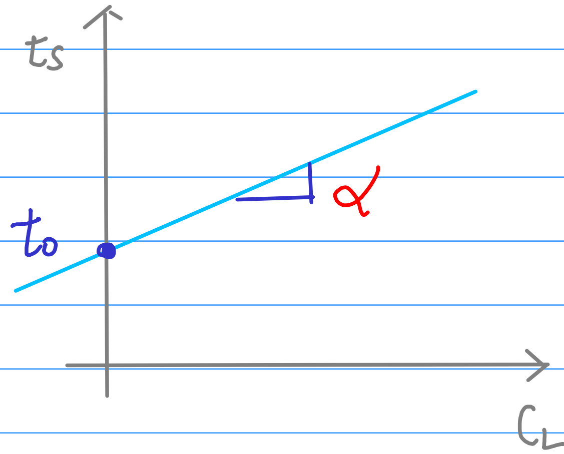
$$\tau = R\,C_{out} = R\,(C_{par} + C_L)$$

Generic Switching Delay

$$t_s = t_0 + \alpha C_L \quad \Rightarrow \quad t_s = t_r = t_f$$

Generic Switching Delay

$$t_s = t_0 + \alpha C_L$$



t_0 : zero delay

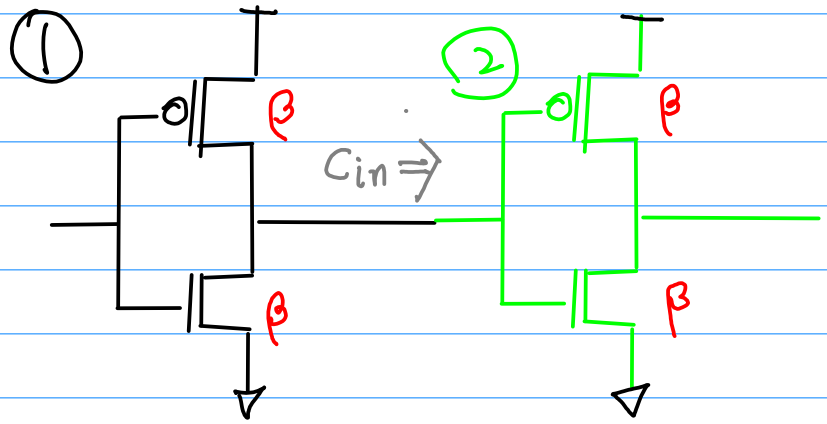
α : slope

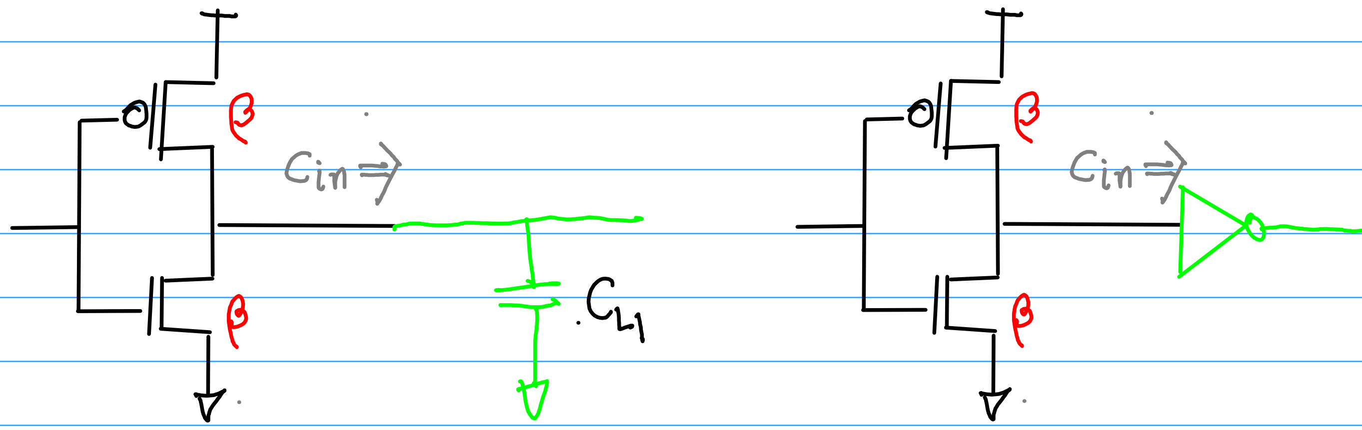
$$t \approx RC$$

$$\alpha \propto \frac{1}{\beta(V_{DD} - V_T)}$$

C_L

MODEL





reference case $C_{in} = C_{L1}$

Generic Switching Delay of (1)

$$t_{s1} = t_0 + \alpha C_{L1}$$

$$= t_0 + \alpha C_{in}$$

$$C_{in} = C_{Gn} + C_{Gp}$$

$$= C_{ox}(A_{Gn} + A_{Gp})$$ A: gate area

the channel length L assumed

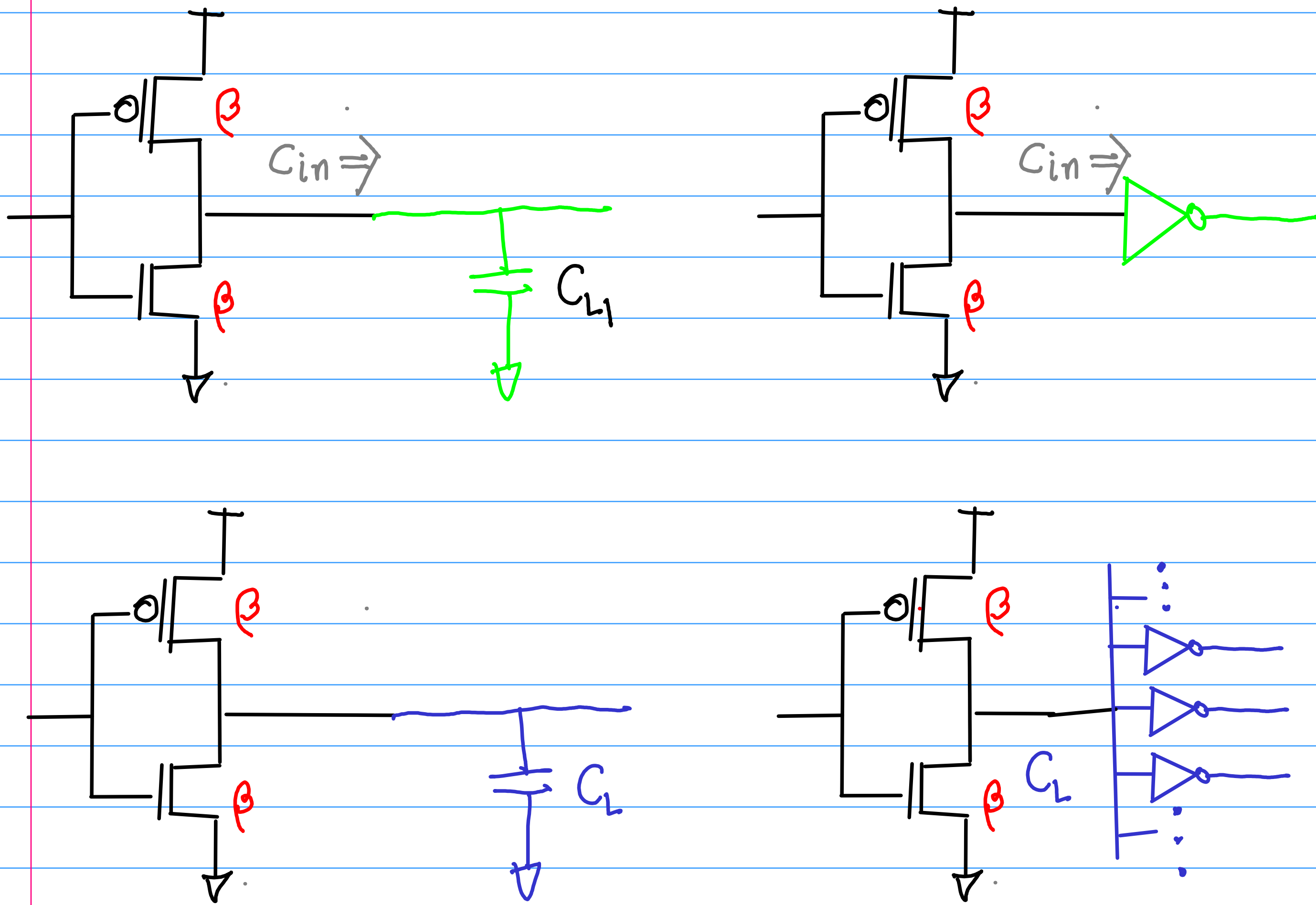
$$C_{in} = C_{ox} L (W_n + W_p)$$

$$= C_{ox} L (W_n + r W_p)$$

$$= C_{ox} L W_n \cdot (1 + r)$$

$$= C_{Gn} (1+r)$$

When $C_L >> C_{in}$



to minimize t_s

$\alpha\downarrow \Rightarrow R\downarrow \Rightarrow \beta\uparrow \Rightarrow$ bigger size

speed v.s. area tradeoff

$$t_s = t_0 + \alpha C_L \qquad t \approx RC$$

$$\alpha \propto \frac{1}{\beta(V_{DD}-V_T)} \qquad C_L$$

MODEL

to minimize t_s

$\alpha \downarrow \Rightarrow R \downarrow \Rightarrow \beta \uparrow \Rightarrow$ bigger size

speed v.s. area tradeoff

Scaling Factor S

$$\beta' = S\beta$$

$$R' = \frac{R}{S}$$

$$\alpha' = \frac{\alpha}{S}$$

$$t_s = t_0 + \underbrace{\frac{\alpha}{S}}_{R}\,\underbrace{C_L}_{C}$$

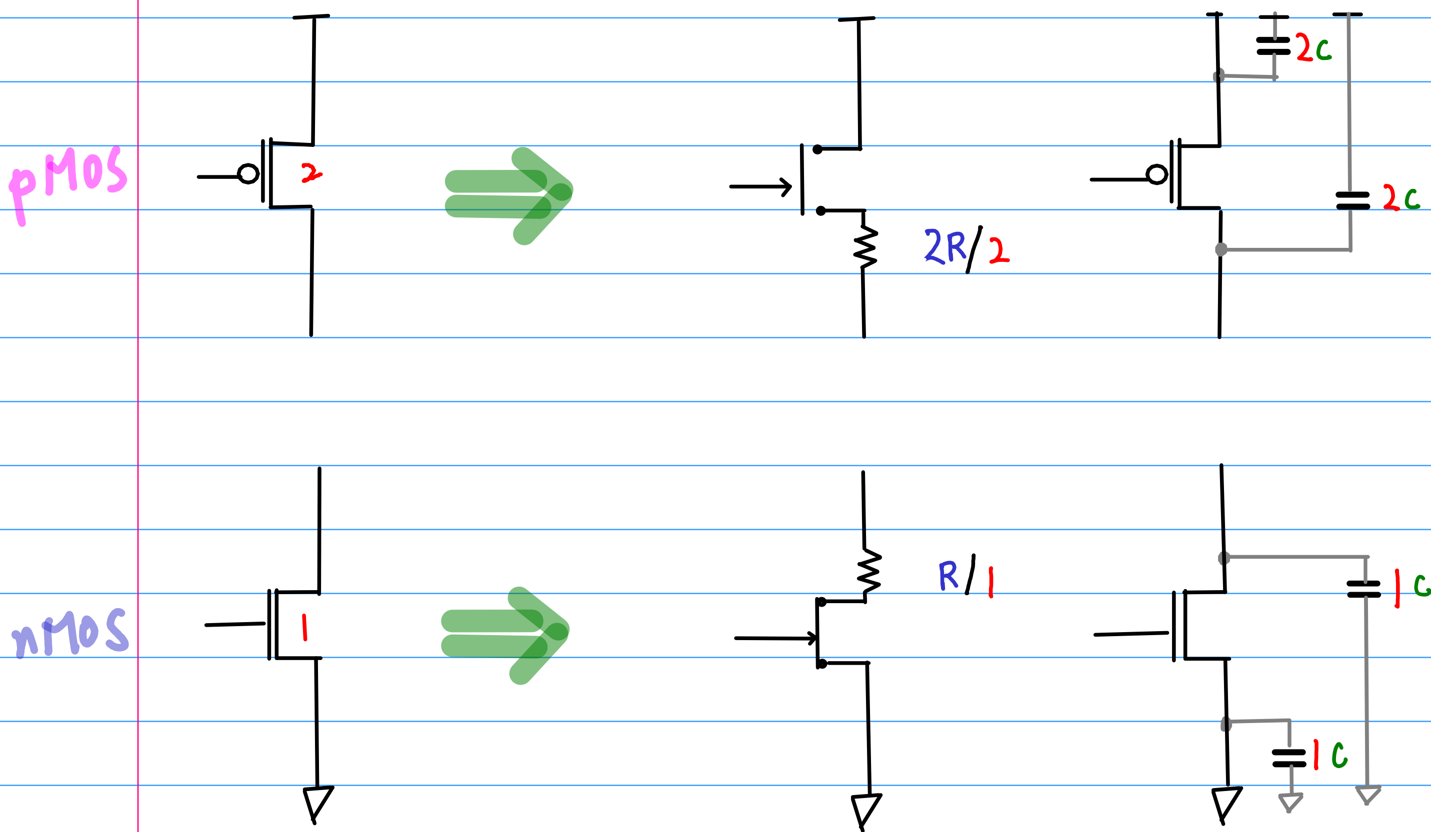
Compensation Factor $\frac{1}{S}$

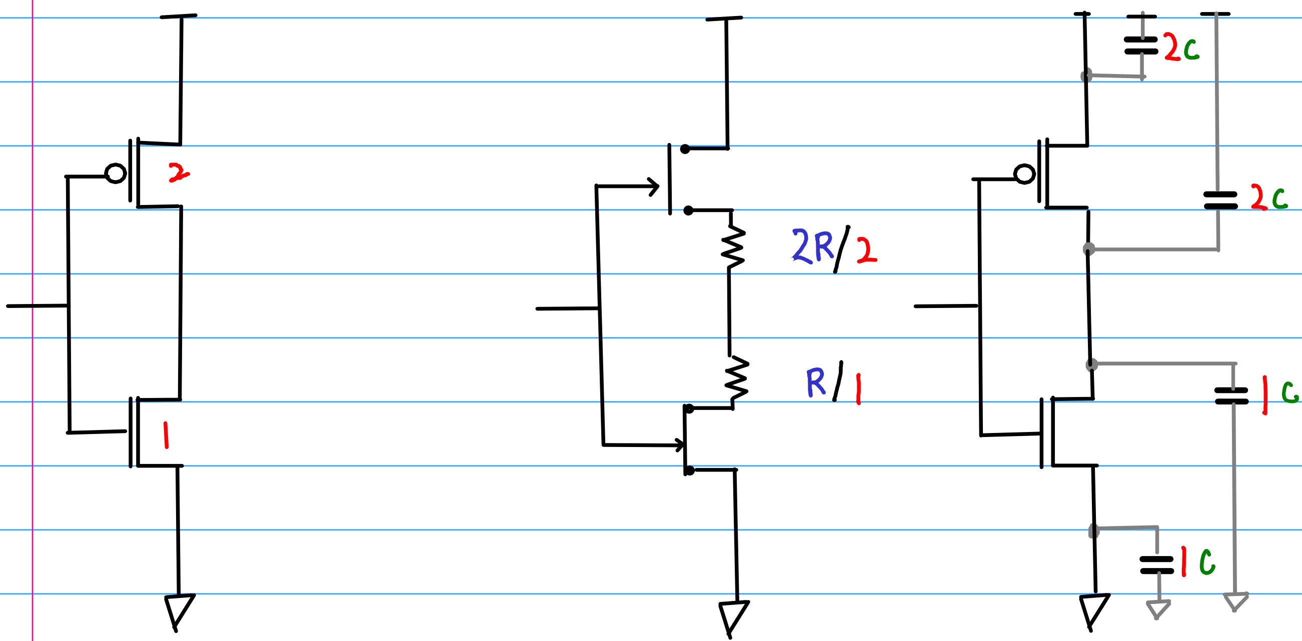
enables a NOT gate drive larger values of C_L

If $C_L = S\,C_{in}$ (increased by the scaling factor S)

then the switching time is the same

RC Delay Model




2
1
2R/2
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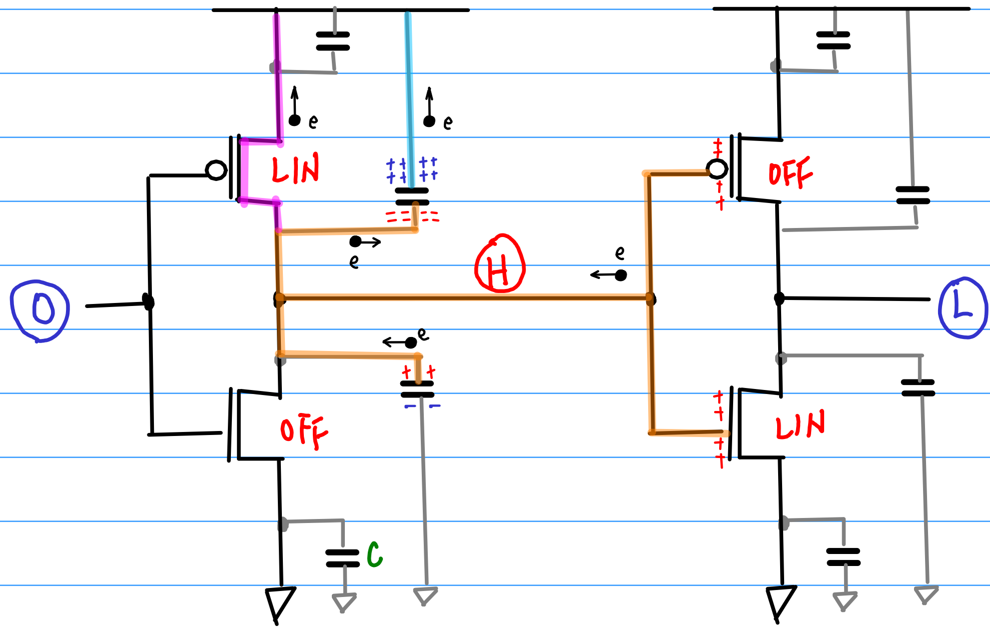
2c
2c
1c
1c


LIN
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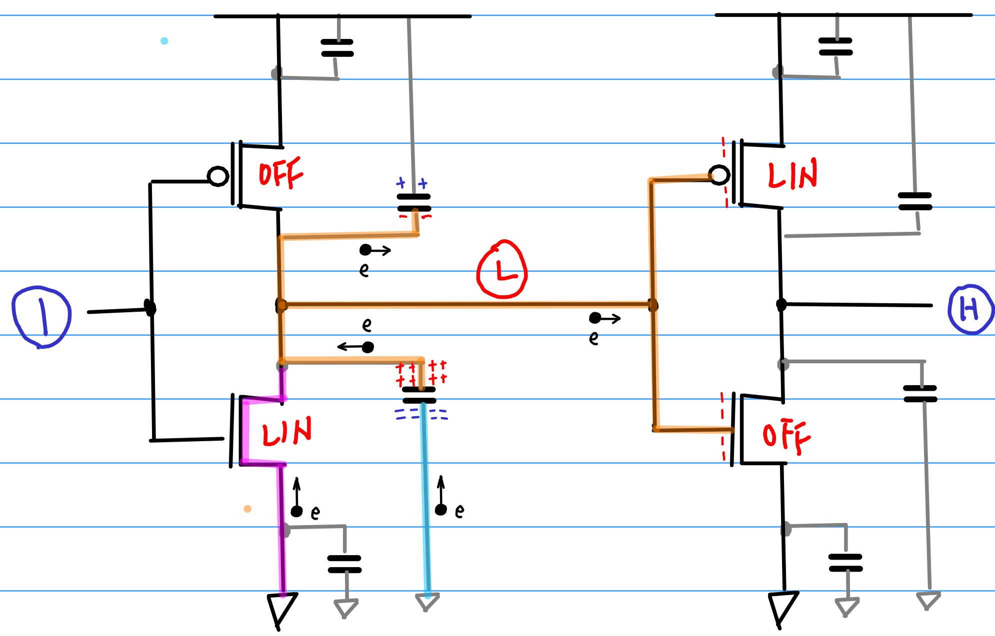
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1
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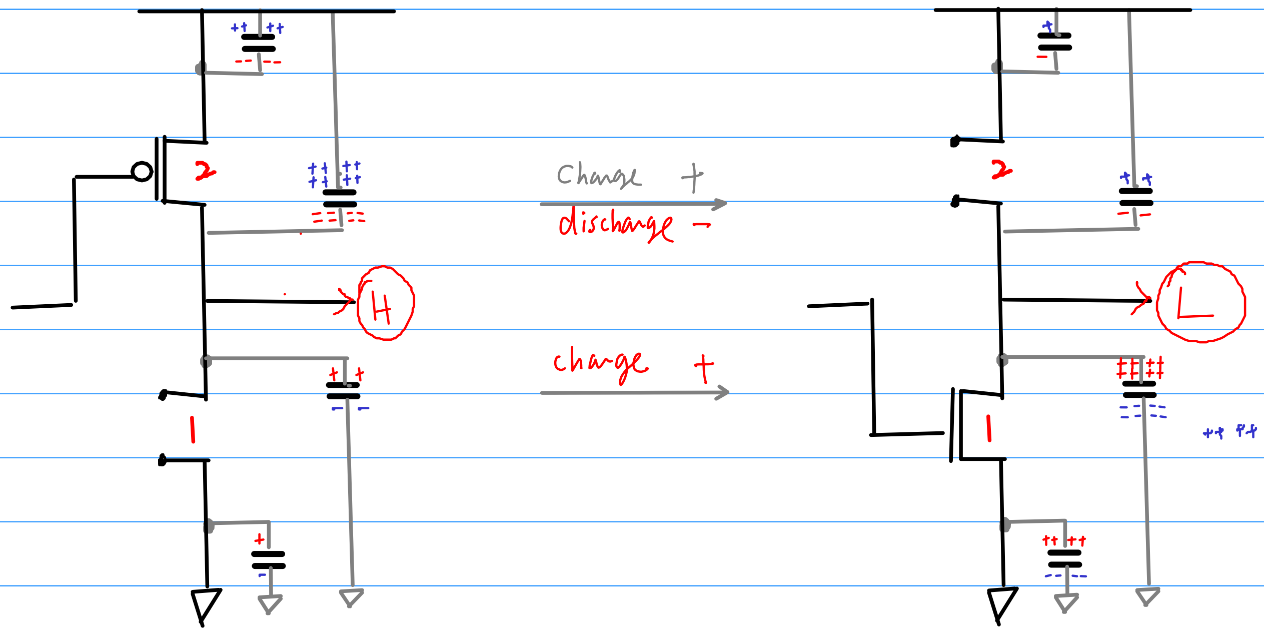
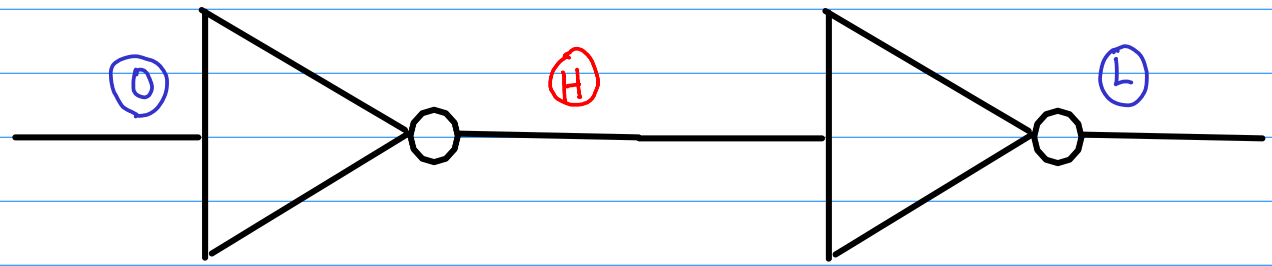
OFF
H


2
H
1
Charge +
discharge −
charge +
2
L
1


0
H
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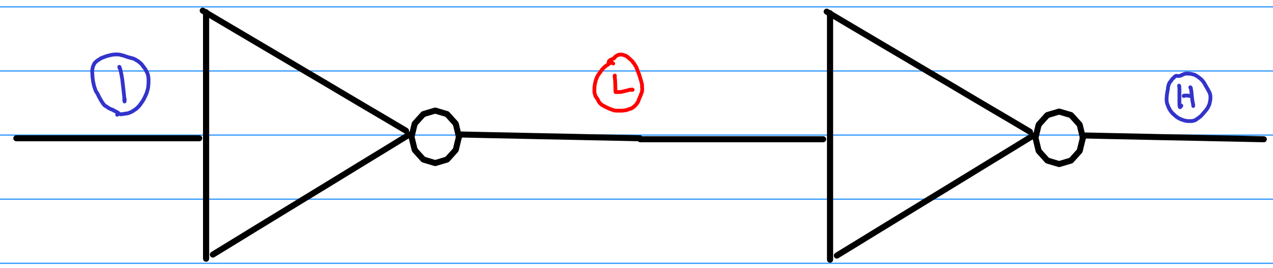
1
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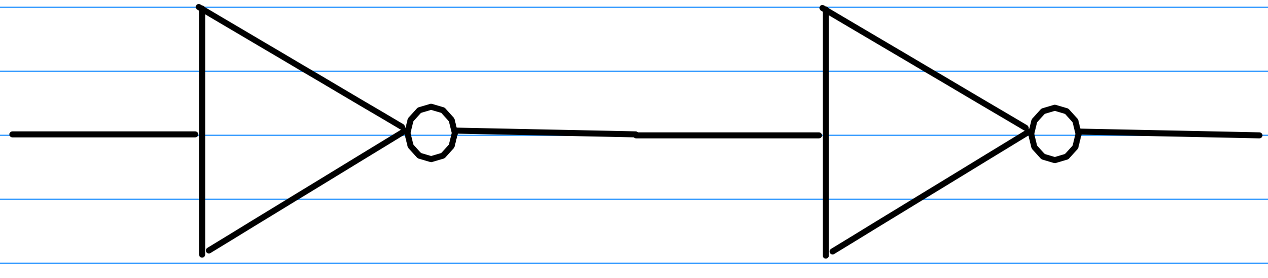

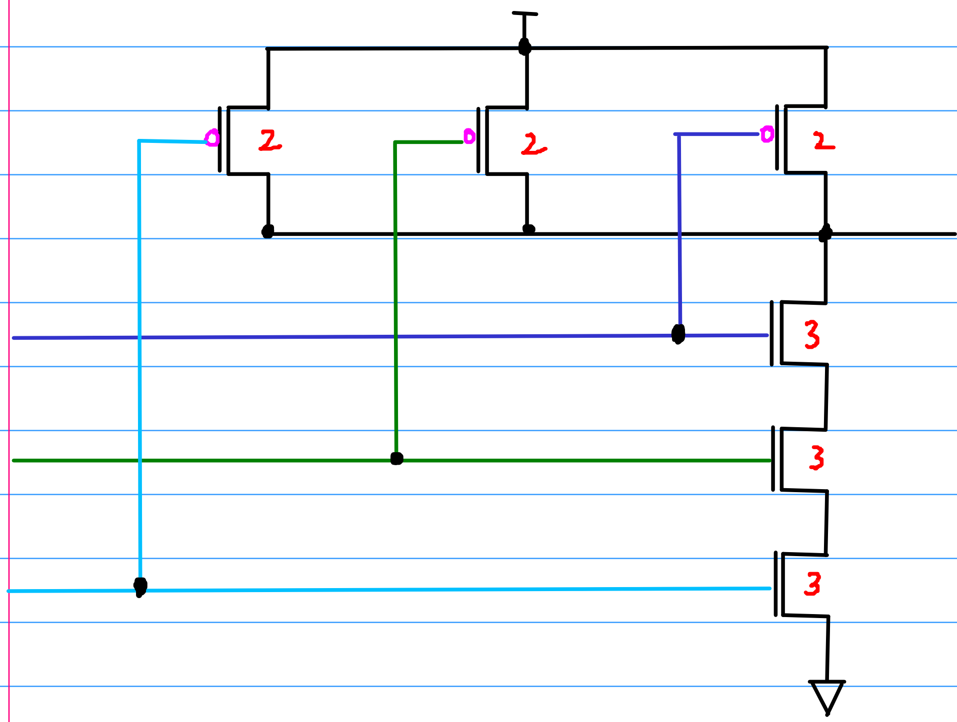
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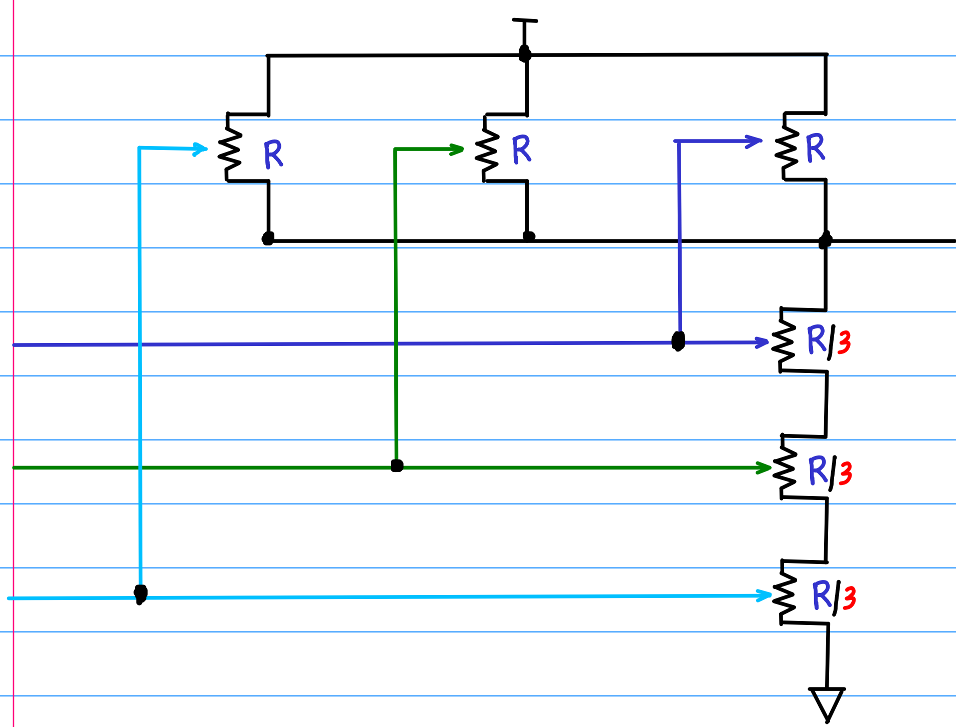
3


R
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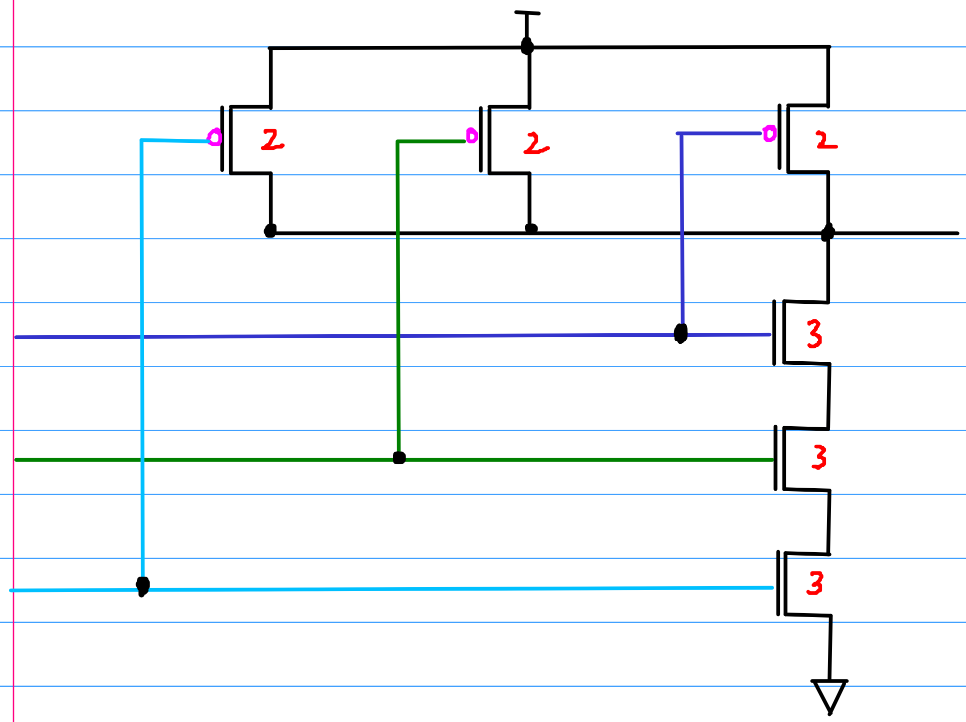

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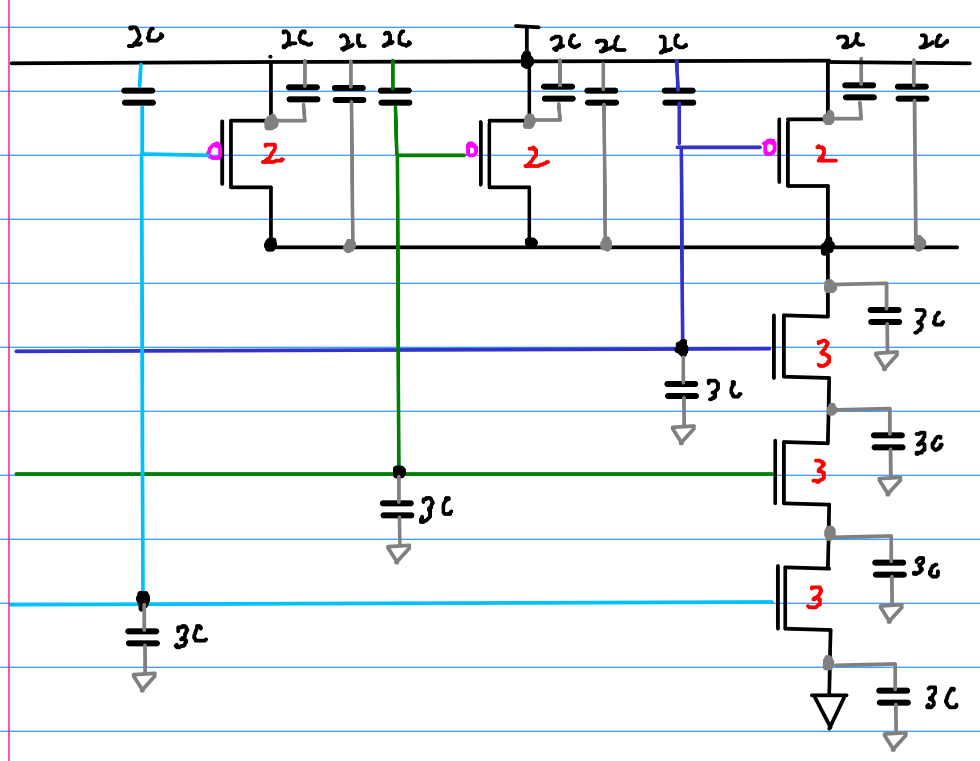

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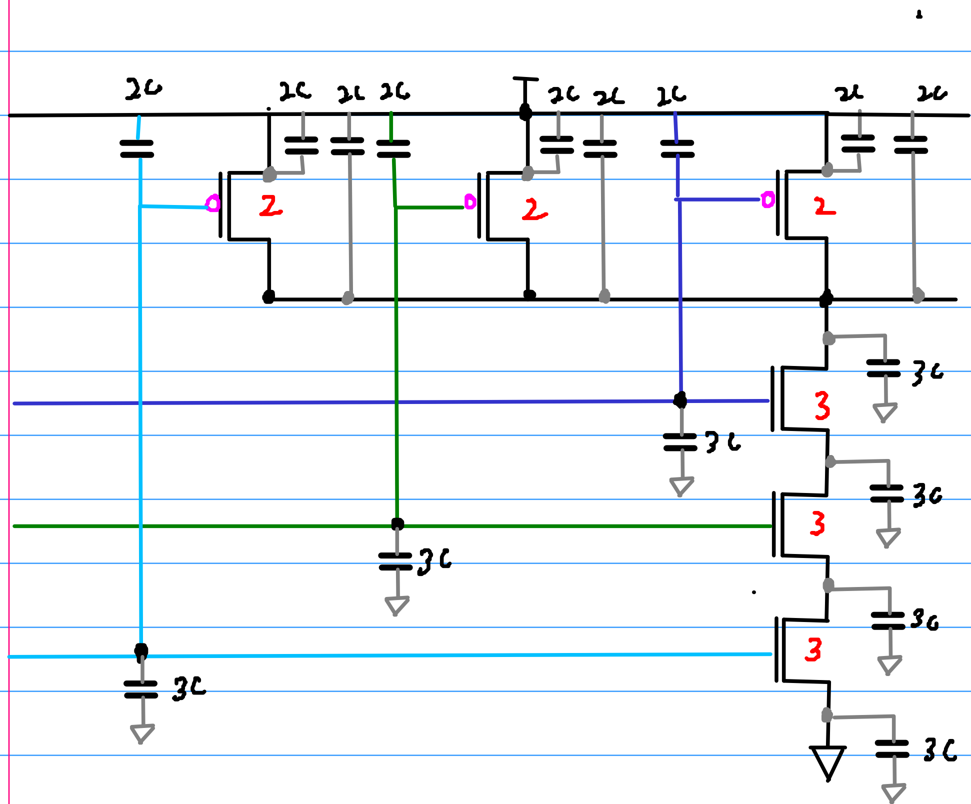

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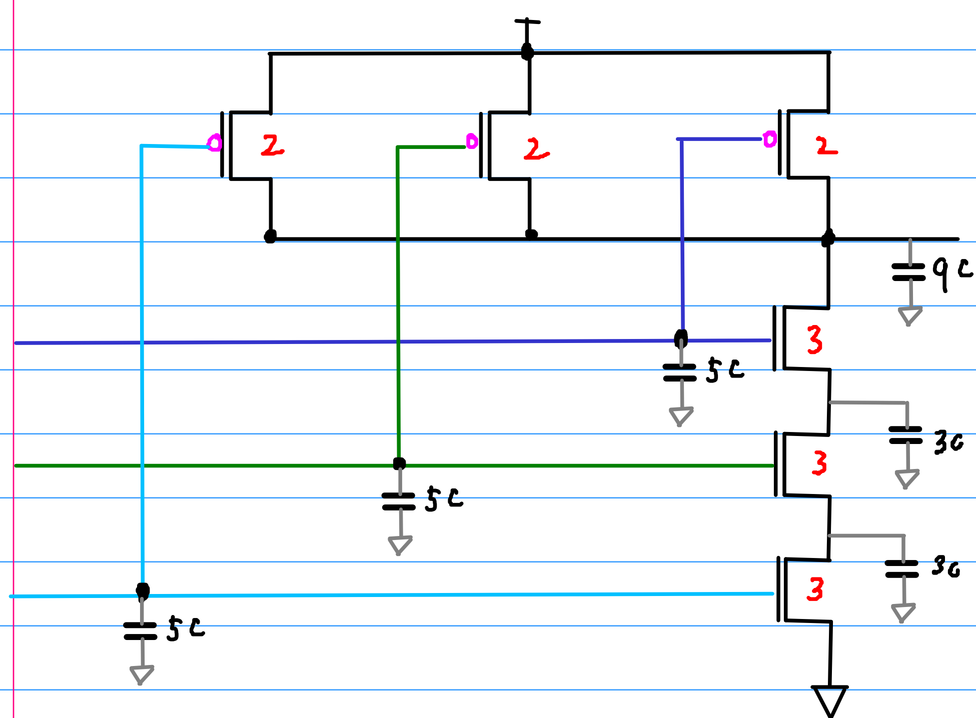
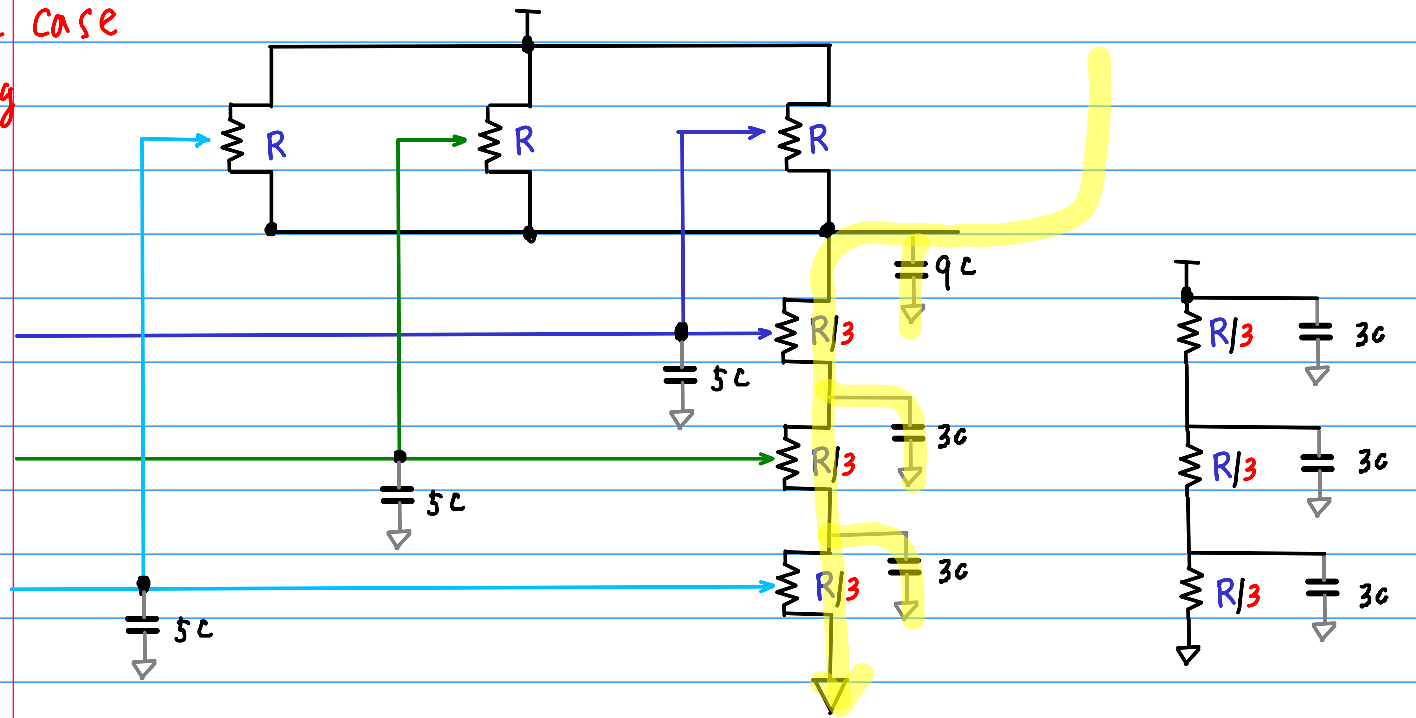
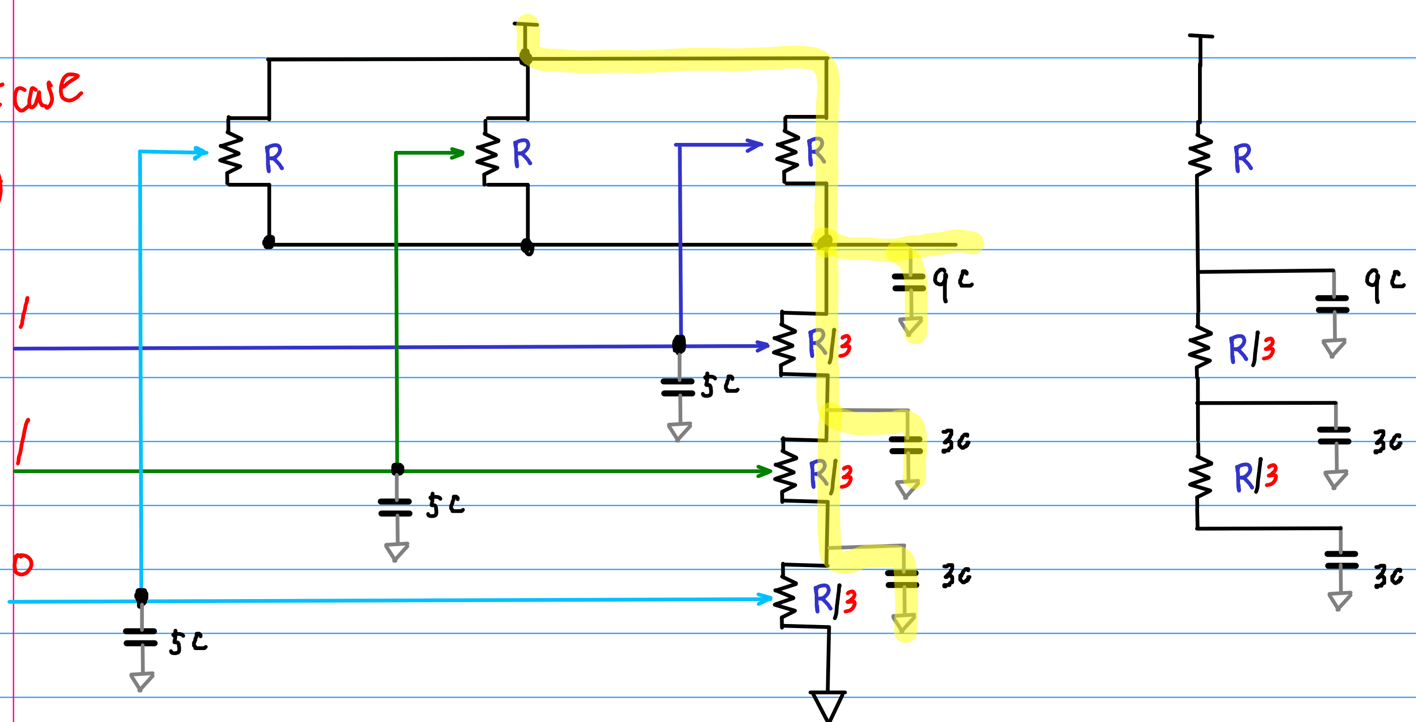


2
2
2
9c
3
3
3
5c
5c
5c
3c
3c

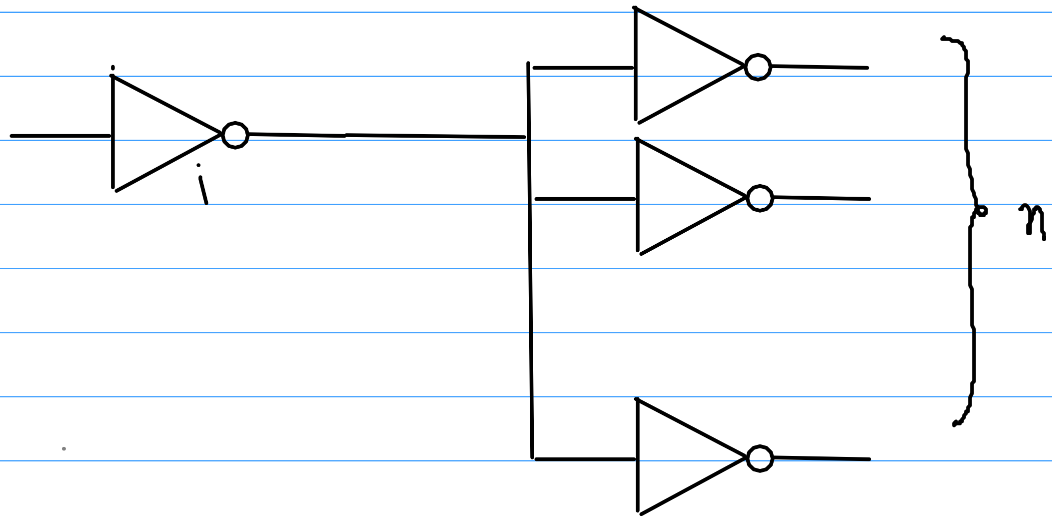
Worst case falling



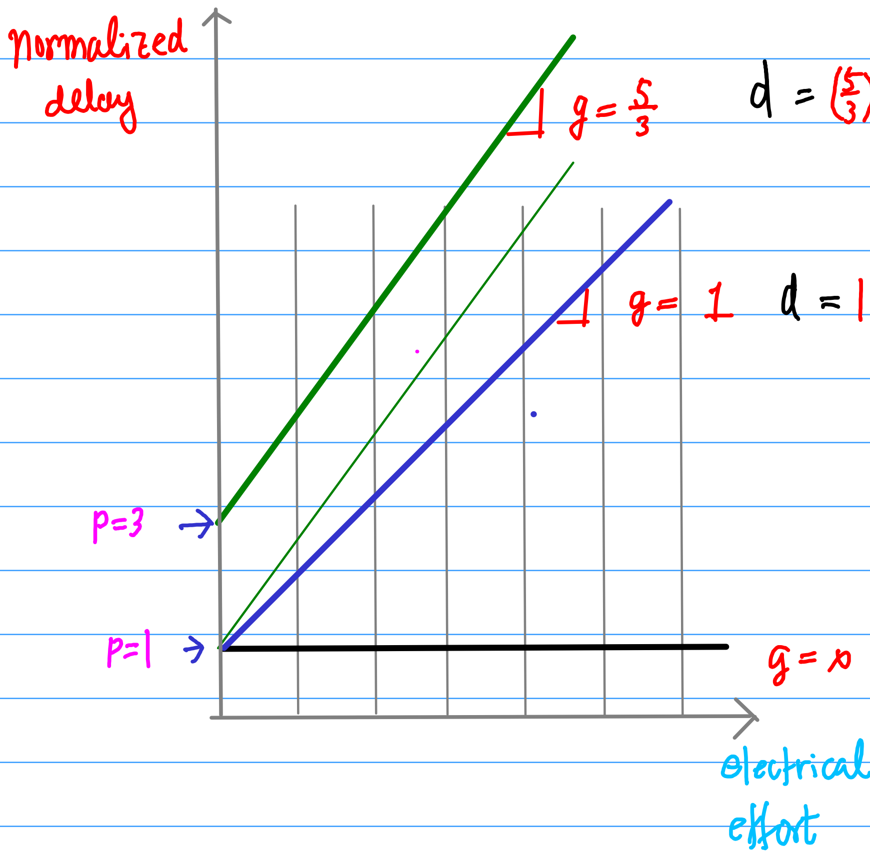
Worst case rising



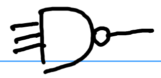
0



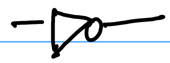
Linear Delay Model



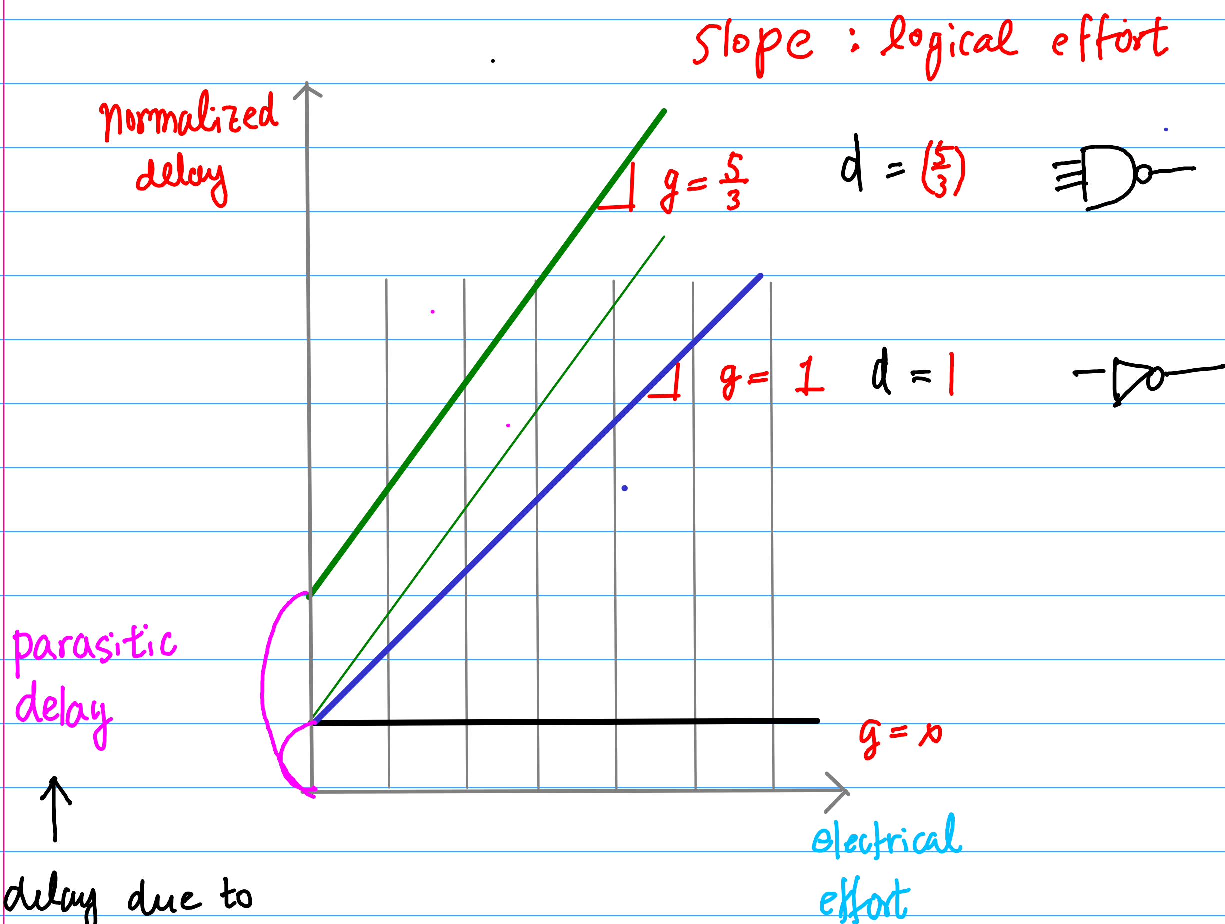
$d = \left(\frac{5}{3}\right) h + 3$



$d = 1 \cdot h + 1$



$h = \frac{C_{out}}{C_{in}}$



↑

delay due to
only internal cap
without external load cap

$$d = g \cdot h + p$$

↑ k ↑ c ↑ c

FET RC Model

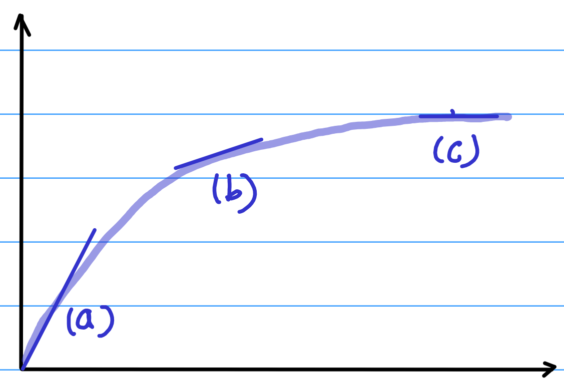
$$R_n = \frac{V_{DSn}}{I_{Dn}}$$

$$I_{Dn} \cong \beta_n (V_{GSn} - V_{Tn}) V_{DSn}$$ (a) small V_{DSn}

$$R_n \cong \frac{1}{\beta_n (V_{GSn} - V_{Tn})}$$

$$R_n = \frac{2}{\beta_n [2(V_{GSn} - V_{Tn}) - V_{DSn}]}$$ (b)

$$R_n = \frac{2V_{DSn}}{\beta_n (V_{GSn} - V_{Tn})^2}$$ (c)



$$R_n \propto \frac{1}{\beta_n}$$

$$\beta_n = k_n' \left(\frac{W}{L}\right)_n$$

$$R_n = \frac{\eta}{\beta_n (V_{DD} - V_{Tn})}$$

$$\eta = 1$$

$$R_n = \frac{1}{\beta_n (V_{DD} - V_{Tn})} \quad \Omega$$

$$C_G = C_{ox} A_G$$
$$= C_{ox} W L'$$

$$C_{GS} = \frac{1}{2} C_G = C_{GD}$$

$$C_0 = C_j A_{pn}$$

$$C = \frac{C_0}{\left(1 + \frac{V_R}{\phi_0}\right)^{m_j}}$$

$$\phi_0 = \left(\frac{kT}{q}\right) \ln\left[\frac{N_d N_a}{n_i^2}\right]$$

$$A_{bot} = XW$$
$$C_{bot} = C_j XW$$
$$A_{sw} = 2(W \times x_j) + 2(X + x_j)$$
$$= x_j P_{sw}$$
$$P_{sw} = 2(W + X)$$
$$C_{sw} = C_{jsw} P_{sw}$$
$$C_{jsw} = C_j x_j$$

$$X \rightarrow X + L_0$$

$$C_n = C_{bot} + C_{sw}$$

$$= C_j A_{bot} + C_{jsw} P_{sw}$$

$$C_n = \frac{C_j A_{bot}}{\left(1+\frac{V}{\phi_0}\right)^{m_j}} + \frac{C_{jsw} P_{sw}}{\left(1+\frac{V}{\phi_{osw}}\right)^{m_{jsw}}}$$

$$C_S = C_{GS} + C_{SB}$$

$$C_D = C_{GD} + C_{DB}$$

pFET Characteristics

$$C_{ox} = \frac{\varepsilon_{ox}}{t_{ox}}$$

$$I_{Dp} = \frac{\beta_p}{2}\left(V_{SGp} - |V_{Tp}|\right)^2$$

$$\beta_p = k'_p \left(\frac{W}{L}\right)_p$$

$$k'_p = \mu_p C_{ox}$$

$$r = \frac{\mu_n}{\mu_p} = 2 \sim 3$$

$$\beta_n = k'_n \left(\frac{W}{L}\right)_n$$

$$\beta_p = k'_p \left(\frac{W}{L}\right)_p$$

$$V_{sat} = V_{SGp} - |V_{Tp}|$$

$$I_{Dp} = \frac{\beta_p}{2}\left[2\left(V_{SGp} - |V_{Tp}|\right)V_{SDp} - V_{SDp}^2\right]$$

$$I_{Dp} = \frac{\beta_p}{2}\left[V_{SGp} - |V_{Tp}|\right]^2$$

$$R_p = \frac{1}{\beta_p\left(V_{DD} - |V_{Tp}|\right)}$$

$$R_p \propto \frac{1}{\beta_p} = \frac{1}{k'_p\left(\frac{W}{L}\right)_p}$$

$$C_{Gp} = C_{ox}\left(WL\right)_p$$

$$C_{GS} = \frac{1}{2} C_{GP} \approx C_{GP}$$

$$C_P = C_j A_{bot} + C_{jsw} P$$

Fall Time Calculation

$$i = -C_{out}\frac{dV_{out}}{dt} = \frac{V_{out}}{R_n}$$

$$V_{out}(t) = V_{DD}\, e^{-t/\tau_n}$$

$$\tau_n = R_n C_{out}$$

$$t = \tau_n \ln\left(\frac{V_{DD}}{V_{out}}\right)$$

$$t_f = t_y - t_x = \tau_n \ln\left(\frac{V_{DD}}{0.1\,V_{DD}}\right) - \tau_n \ln\left(\frac{V_{DD}}{0.9\,V_{DD}}\right)$$
$$= \tau_n \ln(9)$$

$$t_{HL} = t_f \cong 2.2\,\tau_n$$

Rise Time Calculation

$$i = -C_{out}\frac{dV_{out}}{dt} = \frac{V_{DD} - V_{out}}{R_p}$$

$$V_{out}(t) = V_{DD}\left[1 - e^{-t/\tau_p}\right]$$

$$\tau_p = R_p C_{out}$$

$$t = \tau_p \ln\left(\frac{V_{DD}}{V_{out}}\right)$$

$$t_f = t_v - t_u = \tau_p \ln\left(\frac{V_{DD}}{0.1 V_{DD}}\right) - \tau_n \ln\left(\frac{V_{DD}}{0.9 V_{DD}}\right)$$

$$= \tau_p \ln(9)$$

$$t_{LH} = t_r \cong 2.2\tau_p$$

Propagation Delay

$$t_p = \frac{(t_{pf} + t_{pr})}{2}$$

$$t_{pf} = \ln(2) \cdot \tau_n$$
$$t_{pr} = \ln(2) \cdot \tau_p$$

$$t_p \cong 0.35 (\tau_n + \tau_p)$$

$$C_{out} = C_{FET} + C_L$$

$$t_r = 2.2\, R_p\, (C_{FET} + C_L)$$
$$t_f = 2.2\, R_n\, (C_{FET} + C_L)$$

$$t_r = t_{ro} + \alpha_p C_L$$
$$t_f = t_{ro} + \alpha_n C_L$$

$C_L = 0 \rightarrow$ $\quad t_r = t_{ro} \cong 2.2\, R_p\, C_{FET}$

$C_L = 0$ $\quad t_f = t_{ro} \cong 2.2\, R_n\, C_{FET}$

$$\alpha_p = 2.2 R_p = \frac{2.2}{\beta_p (V_{DD} - |V_{Tp}|)}$$
$$\alpha_n = 2.2 R_n = \frac{2.2}{\beta_n (V_{DD} - |V_{Tn}|)}$$

$$\beta_p = k'_p \left(\frac{W}{L}\right)_p$$

$$\beta_n = k'_n \left(\frac{W}{L}\right)_n$$